

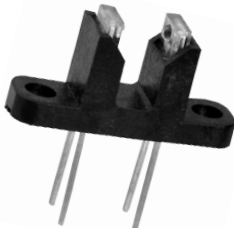
# Slotted Optical Switch

OPB825, OPB825A, OPB825B, OPB825R



**Features:**

- Non-contact switching
- Fast switching speed
- 0.160" (4.06 mm) wide slot
- 0.300" (7.62 mm) lead spacing
- OPB825R—Optimized for ticket dispensers



**Description:**

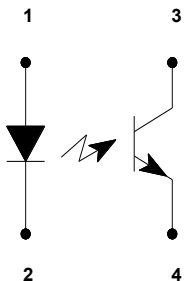
Each OPB825, OPB825A and OPB825B have an infrared LED, while the OPB825R has a Red LED. All devices have a NPN silicon phototransistor mounted in a low-cost black plastic housing on opposite sides of a 0.160" (4.064 mm) wide slot. OPB825 and OPB825R have no mounting tabs and is intended for direct insertion into PCBoards or dual-in-line sockets. OPB825A has one mounting tab on the phototransistor side, while OPB825B has mounting tabs on both sides (two tabs). Phototransistor switching takes place whenever an opaque object passes through the slot.

**Applications:**

- Non-contact interruptive object sensing
- Assembly line automation
- Machine automation
- Equipment security
- Machine safety
- Ticket Sensing

| Ordering Information |                                  |
|----------------------|----------------------------------|
| Part Number          | Description                      |
| OPB825               | Slotted Switch (no tabs) IR-LED  |
| OPB825A              | Slotted Switch (one tab) IR-LED  |
| OPB825B              | Slotted Switch (two tabs) IR-LED |
| OPB825R              | Slotted Switch (no tabs) Red-LED |

| Pin # | Description | Pin # | Description |
|-------|-------------|-------|-------------|
| 1     | Anode       | 3     | Collector   |
| 2     | Cathode     | 4     | Emitter     |



RoHS

General Note  
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## Electrical Specifications

**Absolute Maximum Ratings** ( $T_A=25^{\circ}\text{C}$  unless otherwise noted)

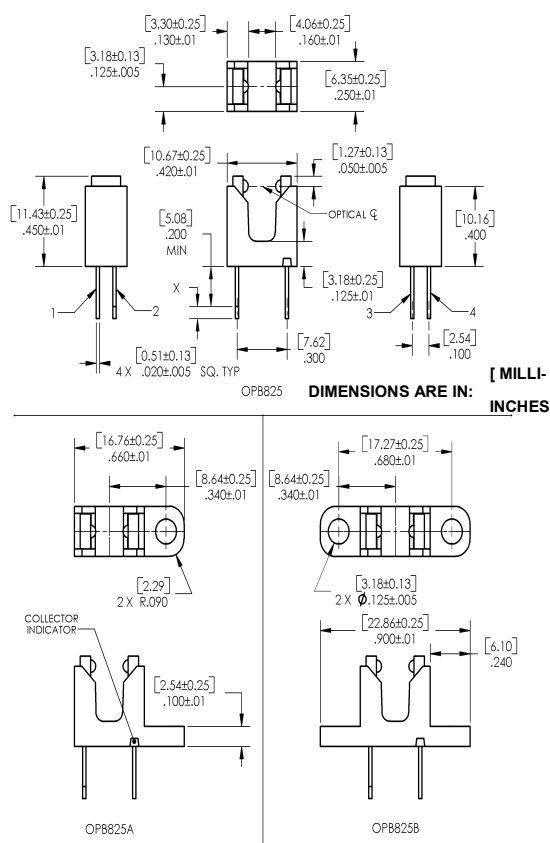
|                                                                                                            |                                                |
|------------------------------------------------------------------------------------------------------------|------------------------------------------------|
| Storage & Operating Temperature Range                                                                      | $-40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$ |
| Lead Soldering Temperature [1/16 inch (1.6mm) from the case for 5 sec. with soldering iron] <sup>(1)</sup> | $260^{\circ}\text{C}$                          |

### Input Diode

|                                                             | OPB825—A—B | OPB825R |
|-------------------------------------------------------------|------------|---------|
| Forward DC Current                                          | 50 mA      | 40 mA   |
| Peak Forward Current (1 $\mu\text{s}$ pulse width, 300 pps) | 3 A        | -       |
| Reverse DC Voltage                                          | 2 V        | 2 V     |
| Power Dissipation <sup>(2)</sup>                            | 100 mW     | 100 mW  |

### Output Phototransistor

|                                  | OPB825—A—B | OPB825R |
|----------------------------------|------------|---------|
| Collector-Emitter Voltage        | 30 V       | 24 V    |
| Emitter-Collector Voltage        | 5 V        | 0.4 V   |
| Collector DC Current             | 30 mA      | 30 mA   |
| Power Dissipation <sup>(2)</sup> | 100 mW     | 100 mW  |



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## OPB825, OPB825A, OPB825B

Electrical Characteristics ( $T_A = 25^\circ\text{C}$  unless otherwise noted)

| SYMBOL | PARAMETER | MIN | TYP | MAX | UNITS | TEST CONDITIONS |
|--------|-----------|-----|-----|-----|-------|-----------------|
|--------|-----------|-----|-----|-----|-------|-----------------|

**Input Diode** (See OP240 for additional information)

|       |                 |   |   |     |               |                      |
|-------|-----------------|---|---|-----|---------------|----------------------|
| $V_F$ | Forward Voltage | - | - | 1.6 | V             | $I_F = 20\text{ mA}$ |
| $I_R$ | Reverse Current | - | - | 100 | $\mu\text{A}$ | $V_R = 2\text{ V}$   |

**Output Phototransistor** (See OP550 for additional information)

|               |                                     |    |   |     |    |                                                |
|---------------|-------------------------------------|----|---|-----|----|------------------------------------------------|
| $V_{(BR)CEO}$ | Collector-Emitter Breakdown Voltage | 30 | - | -   | V  | $I_C = 1\text{ mA}$                            |
| $V_{(BR)ECO}$ | Emitter-Collector Breakdown Voltage | 5  | - | -   | V  | $I_E = 100\text{ }\mu\text{A}$                 |
| $I_{CEO}$     | Collector Dark Current              | -  | - | 100 | nA | $V_{CE} = 10\text{ V}$ , $I_F = 0$ , $E_E = 0$ |

**Combined**

|               |                              |     |   |      |    |                                                       |
|---------------|------------------------------|-----|---|------|----|-------------------------------------------------------|
| $V_{CE(SAT)}$ | Collector-Emitter Saturation | -   | - | 0.4  | V  | $I_C = 250\text{ }\mu\text{A}$ , $I_F = 20\text{ mA}$ |
| $I_{C(ON)}$   | On-State Collector Current   | 1.0 | - | 45.0 | mA | $I_F = 20\text{ mA}$ , $V_{CE} = 10\text{ V}$         |

## OPB825R

Electrical Characteristics ( $T_A = 25^\circ\text{C}$  unless otherwise noted)

| SYMBOL | PARAMETER | MIN | TYP | MAX | UNITS | TEST CONDITIONS |
|--------|-----------|-----|-----|-----|-------|-----------------|
|--------|-----------|-----|-----|-----|-------|-----------------|

**Input Diode** (See OVLAS6CB8 for additional information)

|       |                 |   |     |     |               |                      |
|-------|-----------------|---|-----|-----|---------------|----------------------|
| $V_F$ | Forward Voltage | - | 2.3 | 2.6 | V             | $I_F = 20\text{ mA}$ |
| $I_R$ | Reverse Current | - | -   | 100 | $\mu\text{A}$ | $V_R = 5\text{ V}$   |

**Output Phototransistor** (See OP750 for additional information)

|               |                                     |     |   |     |    |                                                |
|---------------|-------------------------------------|-----|---|-----|----|------------------------------------------------|
| $V_{(BR)CEO}$ | Collector-Emitter Breakdown Voltage | 24  | - | -   | V  | $I_E = 100\text{ }\mu\text{A}$ , $E_E = 0$     |
| $V_{(BR)ECO}$ | Emitter-Collector Breakdown Voltage | 0.4 | - | -   | V  | $I_E = 100\text{ }\mu\text{A}$ , $E_E = 0$     |
| $I_{CEO}$     | Collector Dark Current              | -   | - | 100 | nA | $V_{CE} = 10\text{ V}$ , $I_F = 0$ , $E_E = 0$ |

**Combined**

|              |                             |     |   |      |    |                                                  |
|--------------|-----------------------------|-----|---|------|----|--------------------------------------------------|
| $I_{C(OFF)}$ | OFF-State Collector Current | -   | - | 0.5  | mA | $I_F = 0.80\text{ mA}$ , $V_{CE} = 5.0\text{ V}$ |
| $I_{C(ON)}$  | On-State Collector Current  | 2.5 | - | 16.0 | mA | $I_F = 8.00\text{ mA}$ , $V_{CE} = 0.5\text{ V}$ |

Notes:

- (1) RMA flux is recommended. Duration can be extended to 10 seconds maximum when flow soldering.
- (2) Derate linearly  $1.67\text{ mW}/^\circ\text{C}$  above  $25^\circ\text{C}$ .
- (3) All parameters tested using pulse techniques.
- (4) Methanol or isopropanol are recommended as cleaning agents. Plastic housing is soluble in chlorinated hydrocarbons and ketones.
- (5) Simulates optical path blocked with thick paper

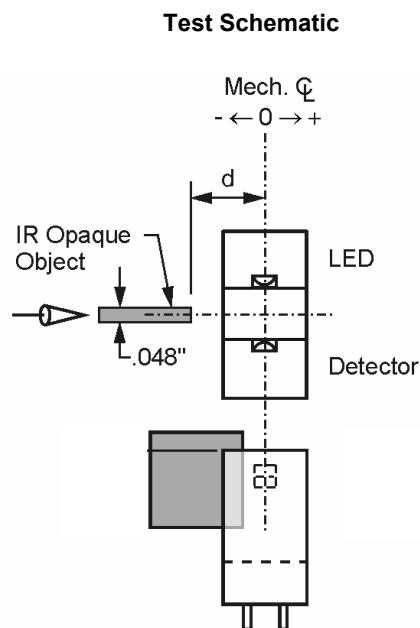
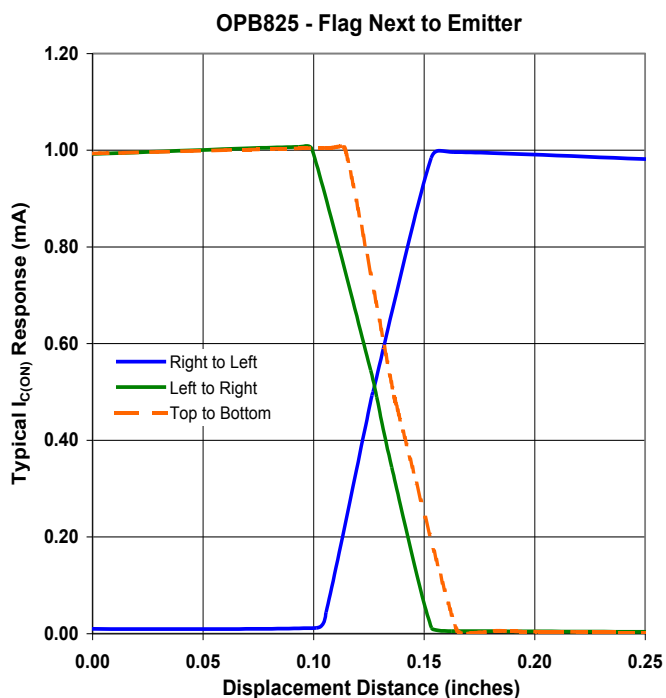
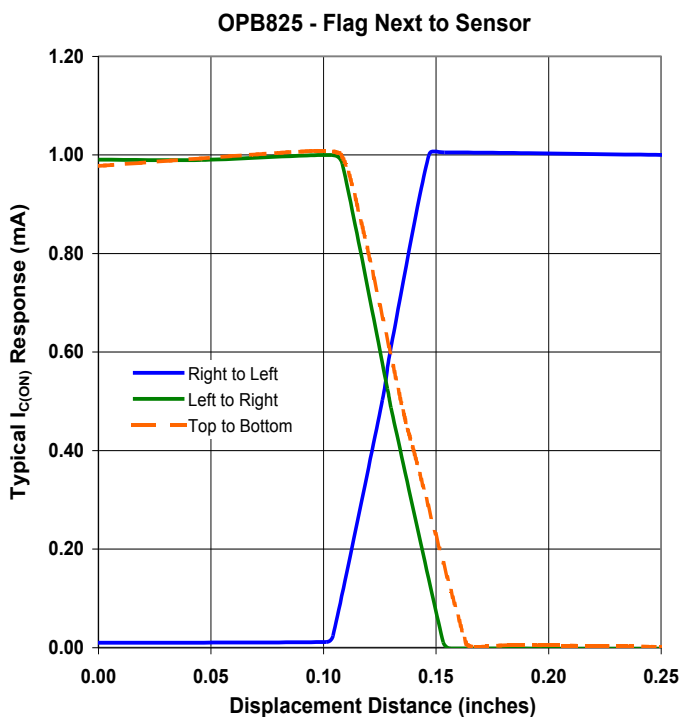
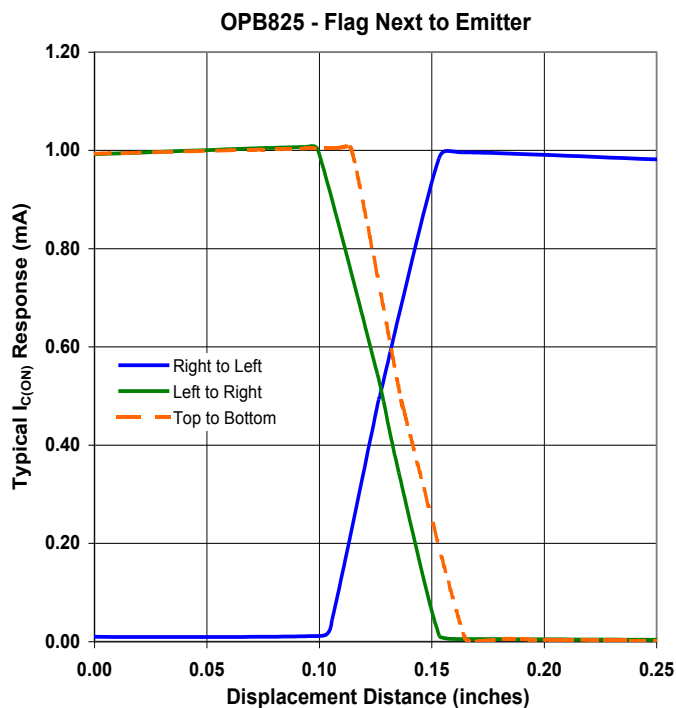
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